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AAP Gen 7 (TO-240AA) Power Modules Standard Diodes, 80 A



AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	80 A				
Туре	Modules - Diode, High Voltage				
Package	AAP Gen 7 (TO-240AA)				
Circuit configuration	Two diodes doubler circuit, two diodes common cathode, two diodes common anode, single diode				

MECHANICAL DESCRIPTION

The AAP Gen 7 (TO-240AA), new generation of AAP module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- High voltage
- Industrial standard package
- Low thermal resistance



- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
1		80	A		
IF(AV)	T _C	110	°C		
I _{F(RMS)}		126			
1	50 Hz	1500	A		
IFSM	60 Hz	1570			
l ² t	50 Hz	11.25	kA ² s		
1-1	60 Hz	10.26	KA-S		
l²√t		112.5	kA ² √s		
V _{RRM}	Range	400 to 1600	V		
T _{Stg} , T _J		-40 to +150	°C		

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA			
	04	400	500				
	06	600	700				
	08	800	900				
VS-VSK.71	10	1000	1100	10			
	12	1200	1300				
	14	1400	1500				
	16	1600	1700				

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° condu	180° conduction, half sine wave			A °C
Maximum RMS forward current	I _{F(RMS)}				126	
		t = 10 ms	No voltage		1500	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		1570	А
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1260	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1320	
	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	11.25	
Maximum I ² t for fusing		t = 8.3 ms	reapplied		10.26	kA ² s
Maximum 1-t for fusing		t = 10 ms	100 % V _{RRM}		7.95	KA-S
		t = 8.3 ms	reapplied		7.23	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	112.5	kA ^{2√} s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	I _{F(AV)}), T _J = T _J maximum	0.73	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)})$	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			v
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum			3.22	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			2.89	11152
Maximum forward voltage drop	V _{FM}	$I_{FM} = \pi \times I_{F(r)}$	_{AV)} , T _J = 25 °C, 1	t _p = 400 μs square wave	1.6	V

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	10	mA		
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V		



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	BOL TEST CONDITIONS		UNITS	
Junction and storage temp	erature range	T _J , T _{Stg}		-40 to +150	°C	
Maximum internal thermal junction to case per leg	resistance,	R _{thJC}	DC operation	0.28		
Typical thermal resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.1	°C/W	
	to heatsink		A mounting compound is recommended and the	4		
Mounting torque ± 10 % busbar			torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	Nm	
Approximate weight				75	g	
Approximate weight				2.7	oz.	
Case style			JEDEC®	AAP Gen 7	(TO-240AA)	

DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION					
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.71	0.075	0.088	0.113	0.155	0.228	0.06	0.094	0.12	0.158	0.23	°C/W

Note

Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

Maximum average forward power loss (W)

160

140

120

100

80

60

40

20

0

1400

1200

1000

800

600

0

1^{80°} 120

90

60 30°

RMS limi

20

40 60 80

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DC

Ø

Conduction Period

100 120

_Initial Tj = Tj max

@ 60 Hz 0.0083 s @ 50 Hz 0.0100s

140

100

Per leg, Tj = 150°C

Average forward current (A)

Fig. 4 - Foward Power Loss Characteristics

At any rated load condition and with

rated Vrrm applied following surge

10

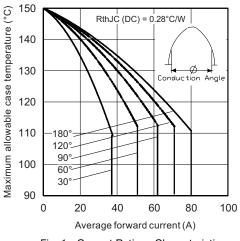
Versus Pulse Train Duration

Initial Tj = 150°C

No Voltage Reapplied

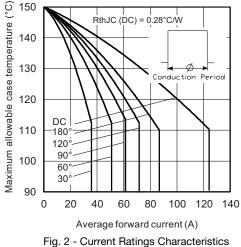
Rated Vrrm reapplied

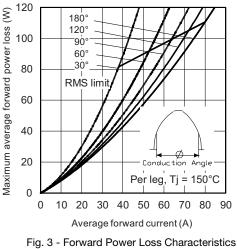
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Fig. 1 - Current Ratings Characteristics

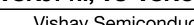


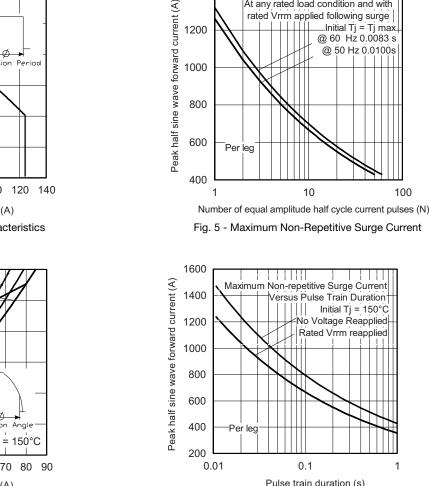


1000 800 600 400 Per lec 200 0.1 0.01

Pulse train duration (s)

Fig. 6 - Maximum Non-Repetitive Surge Current



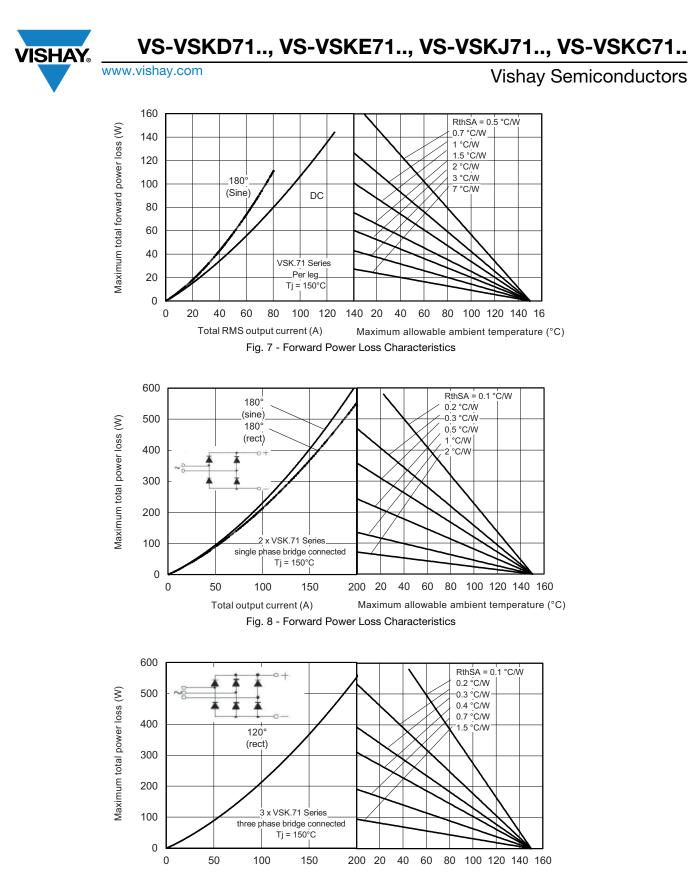


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Total output current (A) Maximum allowable ambient temperature (°C)

Fig. 9 - Forward Power Loss Characteristics



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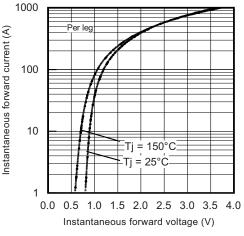


Fig. 10 - Forward Voltage Characteristics

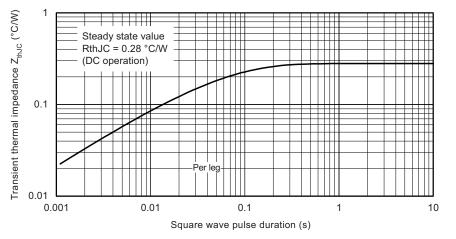


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

VS-VS **Device code** Κ D 71 1 16 2 (3) (4) 1 5 Vishay Semiconductors product 2 Module type 3 Circuit configuration (see Circuit Configuration table) 4 Current code (80 A) 5 Voltage code (see Voltage Ratings table)

Note

• To order the optional hardware go to www.vishay.com/doc?95172

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CIRCUIT CONFIGURATION					
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING			
Two diodes doubler circuit	D				
Two diodes common cathode	С				
Two diodes common anode	J				
Single diode	E				

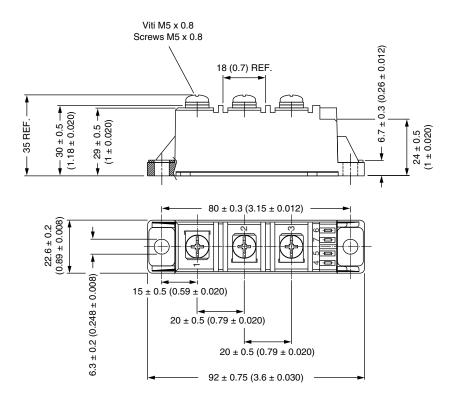
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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